
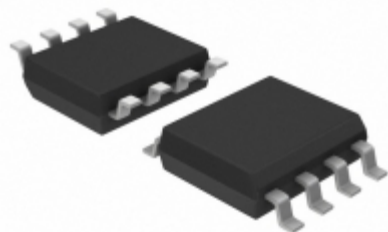






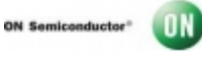

	<h2 style="color: red;">NTMSD2P102LR2</h2>
	<p>Hersteller-Teilenummer: NTMSD2P102LR2</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET P-CH 20V 2.3A 8-SOIC</p> <p>Datenblätter:  NTMSD2P102LR2.pdf</p> <p>RoHs Status: Enthält Blei / RoHS nicht konform</p> <p>Lagerzustand: New original, 839 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTMSD2P102LR2
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET P-CH 20V 2.3A 8-SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	839 pcs Stock
Serie	FETKY™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SOIC
Verlustleistung (max)	710mW (Ta)
Typ FET	P-Channel
FET-Merkmal	Schottky Diode (Isolated)
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.3A (Ta)
Rds On (Max) @ Id, Vgs	90 mOhm @ 2.4A, 4.5V
VGS (th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	18nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	750pF @ 16V
Verpackung	Tape & Reel (TR)



















































NTMSD2P102LR2 ist neu im Original, Suche NTMSD2P102LR2 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTMSD2P102LR2 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTMSD2P102LR2: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTMS7N03R2G. ON NTMS7N03R2G. ON</p>	 <p>NTMSD2P102LR2G AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 2.3A 8-SOIC</p>	 <p>NTMS7N03R2G SOP8 ON NTMS7N03R2G SOP8 ON</p>	 <p>NTMSD2P10LR2G AMI Semiconductor / ON Semiconductor NTMSD2P10LR2G ON</p>
 <p>NTMS7N03R2 AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 4.8A 8-SOIC</p>	 <p>NTMSD3P102R2 AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 2.34A 8-SOIC</p>	 <p>NTMS7N03R2R2G AMI Semiconductor / ON Semiconductor NTMS7N03R2R2G ON</p>	 <p>NTMSD2P102R2SG AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 2.3A 8-SOIC</p>

heiße Teile

Mehr

 NTMS4503NR2G	 NTMS4700NR	 NTMS4700NR2G	 NTMS4704NR2G	 NTMS4705NR2G
 NTMS4706NR2G	 NTMS4800NR2G	 NTMS4801N	 NTMS4801NR2G	 NTMS4802N
 NTMS4802NR2G	 NTMS4807N	 NTMS4807NR2G	 NTMS4816N	 NTMS4816NG
 NTMS4816NR2G	 NTMS4840NR2G	 NTMS4872NR2G	 NTMS4873NFR2G	 NTMS4916AS001
 NTMS4916N	 NTMS4916NR2G	 NTMS4916UT001	 NTMS4917NR2G	 NTMS4917UT001
 NTMS4920N	 NTMS4920NR2G	 NTMS4937N	 NTMS4937NR2G	 NTMS4939N
 NTMS4939NR2G	 NTMS4N01R2	 NTMS4P01R2G	 NTMS5835NL	 NTMS5835NLR2G
 NTMS5838NLR2G	 NTMS5P02	 NTMS5P02R2	 NTMS5P02R2G	 NTMS7N03R2
 NTMS7N03R2G	 NTMS7N03R2R2G	 NTMSD2P102R2	 NTMSD3P102R2	 NTMSD3P102R2SG
 NTMSD3P303R2	 NTMSD6N03R2G	 NTMSD6N303R2	 NTMSD6N303R2G	 NTMSD6N303R2SG

Contact us: Info@Y-IC.com

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